

Evolution of topological surface states of thin HgTe-films with film thickness

Bachelor thesis

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Universität Regensburg

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Hello, my name is Tamara Szecsey and I will now give you a talk about my bachelor thesis topic, the evolution of topological surface states of thin HgTe-films with film thickness.

Table of contents

Introduction

Theory

Results

Conclusion

Evolution of topological surface states of thin HgTe-films with film thickness

Table of contents

└ Table of contents

Introduction

Theory

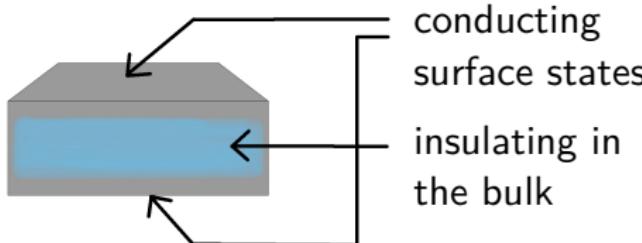
Results

Conclusion

First I will introduce the topic of this thesis, then, in the theory part, I explain characteristics of topological insulators, how to describe a crystal structure and the surfaces so that computational calculations can be performed, the density functional theory and the spin-orbit coupling. In the third part I will talk about the results I got and if we can see topological surface states and finally I present the conclusions.

Introduction

HgTe is a II-VI semiconductor and a topological insulator (TI).¹



TIs are interesting because:

- ▶ spin-momentum locking
- ▶ protected surface states

Calculations were performed using density functional theory (DFT) through FHI-aims.

$0.5\text{nm} \approx$



} $\approx 2.7\text{nm}$

Main goal: Evolution of surface states in different slab thicknesses.

Evolution of topological surface states of thin HgTe-films with film thickness

└ Introduction

└ Introduction

HgTe is mercury-based II-VI(6) semiconductor which appears in zinc-blende structure and it's additionally found to be a topological insulator.

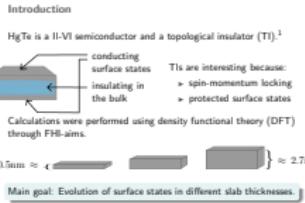
A topological insulator is a material which is insulating in its interior, also called the bulk of a material, and that develops conducting states at the surface.

They are very attractive for potential applications because the spin and the momentum of the electrons at the conducting surfaces are locked. This means, the spin is always perpendicular to the direction of motion of those electrons. The spin-momentum locking makes sure that the surfaces are protected if time-reversal symmetry is preserved. In other words the surface states remain, even for non-magnetic impurities.

The calculations I performed were ab-initio calculations and therefore I used the density functional theory with the exchange-correlation function method PBE through FHI-aims.

HgTe was examined in thin films from approximately 0.5 nm to 2.7 nm, which are 4 to 17 layers of atoms. Surfaces can only be examined in one direction at once. Because otherwise it would went beyond the scope of a bachelor thesis, we chose just one direction of observance, namely the (001) direction.

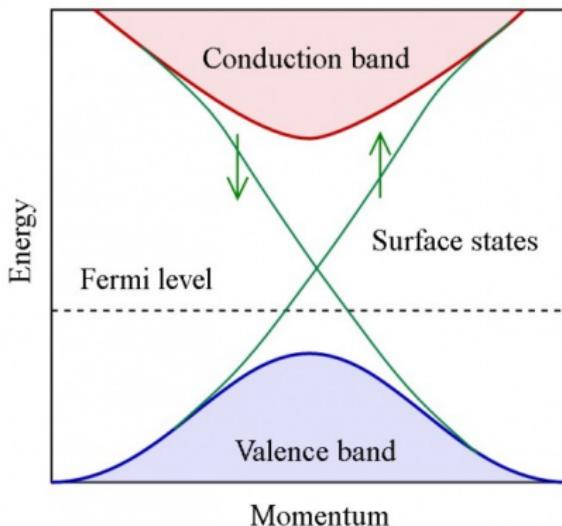
The main goal this thesis pursued was examining the evolution of topological surface states for different slab thicknesses. Therefore I will now explain the theory behind the realization of this examination.



Theory: Topological insulator

2005 Kane and Mele found another class of material:
the topological insulator (TI).

spin-orbit coupling → band inversion → Dirac cone



2D TI:

have quantum spin edge states
found in graphene and HgTe
quantum wells.

3D TI:

strong and weak ones
HgTe is semi metal but under
strain Γ_6 and Γ_8 bands can close
up at Fermi level.

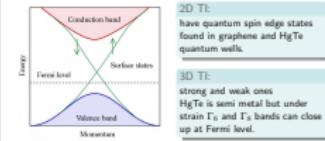
Evolution of topological surface states of thin HgTe-films with film thickness

└ Theory

└ Theory: Topological insulator

Theory: Topological insulator

2005 Kane and Mele found another class of material:
the topological insulator (TI).
spin-orbit coupling → band inversion → Dirac cone



Besides from insulators and conductors, Kane and Mele 2005 found another class of material which is the so-called topological insulator. Most of the unusual properties come from the including of the spin-orbit coupling. This produces the spin-momentum locking mentioned earlier and can lead to band inversion. The spin-momentum locking and time-reversal symmetry prevent backscattering, because for two opposite momentums, the spin is also opposite and the states interfere destructively. In other words, the surface states are protected by time-reversal symmetry. If the surface states close up because of band inversion then a so-called Dirac cone arises like seen in this picture from wikipedia. Here we see the momentum plotted against the energy near Fermi level. The blue line is the valence band and the red one is the conduction band. The surface states in green have a spin locked to their momentum and are forming a Dirac cone because their bands are inverted.

In 2D there were found topological surface states in graphene and HgTe quantum wells which are called Quantum spin edge states based on the Quantum spin hall effect. These quantum wells have non-trivial topological surface states under a certain critical thickness but become trivial insulators as soon as they pass this critical thickness. 3D topological insulators are distinguishable into strong and weak topological insulators where the number of dirac cones is odd for strong and even for weak ones. HgTe normally is a semi metal but under strain its Γ_6 and Γ_8 bands can close up at Fermi level, which means its surface states become topological.

Theory: Crystal and surface description part 1

Translation vector: $\mathbf{R}_i = x_i \mathbf{a}_1 + y_i \mathbf{a}_2 + z_i \mathbf{a}_3$

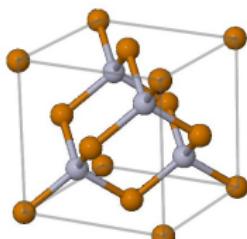
contains basis for lattice forming a unit cell.

Smallest primitive unit cell is the Wigner Seitz cell.

Bravais lattice

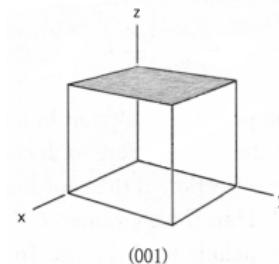
fcc lattice with two atomic basis \rightarrow diamond or zinc-blende structure

Miller indices: (hkl)



	x	y	z
a_1	0	$\frac{a}{2}$	$\frac{a}{2}$
a_2	$\frac{a}{2}$	0	$\frac{a}{2}$
a_3	$\frac{a}{2}$	$\frac{a}{2}$	0
Te	0	0	0
Hg	$\frac{a}{4}$	$\frac{a}{4}$	$\frac{a}{4}$

$$h : k : l = \frac{1}{x} : \frac{1}{y} : \frac{1}{z}$$



Evolution of topological surface states of thin HgTe-films with film thickness

└ Theory

└ Theory: Crystal and surface description part 1

The atoms of a crystal maintain a symmetric pattern that repeats itself in our case into the three spatial dimensions. In order to describe that crystalline structure, we make use of the translation vector R_i which contains information about the coordinates x , y and z of an atom i and the primitive translation vectors a_1 one, a_2 two and a_3 three that form a so-called unit cell. It is a primitive unit cell, if it contains the least possible amount of atoms. The smallest primitive unit cell is called Wigner Seitz cell and has one single atom in its center.

The lattices which are generated by R_i are called Bravais lattice and in three dimensional space there are 14 of them. The face-centered cubic (fcc) lattice with two atomic basis is the structure needed here. If the atoms are of the same species, then it is called a diamond structure, if the atoms are of a different kind of species, it's called a zinc-blende structure. The latter is the one for mercury telluride. Here you can see the basis of it and a picture of a cubic. This is the basis for the bulk calculations. Surfaces however are described by the Miller indices h , k and l which are related to numbers x , y and z , and if one multiplies the basis vector with those numbers, the basis vectors touch the surface. If the basis vector can never touch the surface, then the Miller index is set to zero. This is why this plane (picture) is the (001) plane.

Theory: Crystal and surface description part 1

Translation vector: $R_i = x_i a_1 + y_i a_2 + z_i a_3$

contains basis for lattice forming a unit cell

Smallest primitive unit cell is the Wigner Seitz cell.

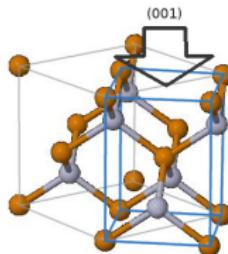
Bravais lattice

fcc lattice with two atomic basis → diamond or zinc-blende structure



Theory: Crystal and surface description part 2

Basis for (001) direction of zinc-blende structure:



	x	y	z
a_1	$\frac{a}{\sqrt{2}}$	0	0
a_2	0	$\frac{a}{\sqrt{2}}$	0
a_3	0	0	a

	x	y	z
Te	0	0	0
Hg	$\frac{a}{2\sqrt{2}}$	0	$\frac{a}{4}$
Te	$\frac{a}{2\sqrt{2}}$	$\frac{a}{2\sqrt{2}}$	$\frac{a}{2}$
Hg	0	$\frac{a}{2\sqrt{2}}$	$\frac{3a}{4}$

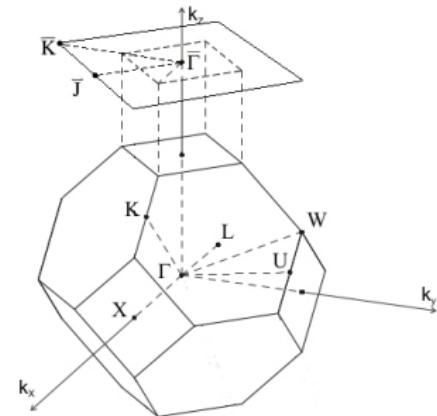
Reciprocal lattice: $e^{i\mathbf{K}\cdot\mathbf{R}} = 1$

\mathbf{K} is reciprocal translation vector.

First Brillouin zone (BZ) is Wigner Seitz cell for reciprocal space.

Super symmetrical points:

$$\bar{\Gamma} = 0; \quad \bar{J} = \frac{1}{2}\mathbf{b}_1; \quad \bar{K} = \frac{1}{2}\mathbf{b}_1 + \frac{1}{2}\mathbf{b}_2$$



Evolution of topological surface states of thin HgTe-films with film thickness

Theory

Theory: Crystal and surface description part 2

For calculations in the (001) direction, it is convention to rotate the unit cell by 45 degrees which gives us another basis for HgTe.

As we say before, the energy bands are obtained by observing the momentum with respect to the energy. The best way to do so is, to use the reciprocal lattice which is the Fourier transform of the real lattice with (formular with e function). K is the reciprocal translation vector with reciprocal lattice vectors b_1 , b_2 and b_3 . The first Brillouin zone is the Wigner Seitz cell for the reciprocal space. It contains so-called high symmetry points, in the picture one can see a Γ in the origin. Every other high symmetry point is indicated by Latin letters. The points with a bar on top are the high symmetry points for the 2D Brillouin zone which we will use for the surface calculations, in concrete: Gamma bar, J bar, K bar.

Theory: Crystal and surface description part 2

Basis for (001) direction of zinc-blende structure:

	a_1	a_2	a_3	a_4	a_5	a_6	a_7	a_8
Hg	$\frac{1}{2}$							
Ts	$\frac{1}{2}$							
Te	$\frac{1}{2}$							

Reciprocal lattice: $e^{i\vec{K}\cdot\vec{R}} = 1$

K is reciprocal translation vector.

First Brillouin zone (BZ) is Wigner

Seitz cell for reciprocal space.

Super symmetrical points:

$$\bar{\Gamma} = 0; \quad \bar{J} = \frac{1}{2}b_1; \quad \bar{K} = \frac{1}{2}b_1 + \frac{1}{2}b_2$$



Theory: Surface modeling

Termination

Two surfaces with symmetric Hg-Hg, Te-Te terminations or antisymmetric Te-Hg terminations.

Add hydrogen atoms in order to saturate dangling bonds.

Number of layers

Odd for symmetric, even for antisymmetric termination.

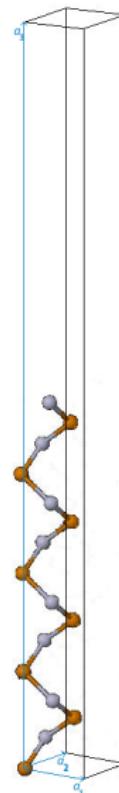
Atoms with same z component are in the same layer.

I studied 3 different thicknesses for each termination.

Supercell approach

Infinite repetition only possible in all directions.

In order to avoid interactions between slabs in k_z direction: add vacuum space.



Evolution of topological surface states of thin HgTe-films with film thickness

└ Theory

└ Theory: Surface modeling

Theory: Surface modeling

Termination

Two surfaces with symmetric Hg-Hg, Te-Te terminations or antisymmetric Te-Hg terminations.

Add hydrogen atoms in order to saturate dangling bonds

Number of layers

Odd for symmetric, even for antisymmetric termination.
Atoms with same z component are in the same layer.
I studied 3 different thicknesses for each termination.

Supercell approach

Infinite repetition only possible in all directions.
In order to avoid interactions between slabs in k_z direction: add vacuum space.



Now I will talk about what we have to consider for simulating the surfaces in (001) direction. At first, there are different possible terminations at the top and the bottom surfaces. Either the terminations are symmetric Hg-Hg or Te-Te, or they are antisymmetric with Te-Hg. I also performed calculations with additional hydrogen atoms at one surface in order to saturate the dangling bonds (the unsatisfied valences on immobilized atoms).

The number of layers corresponds to the kind of termination, it is odd for symmetric and even for antisymmetric ones. In our case, one layer contains every atom with the same z component. And I studied three different numbers of layers or thicknesses for each kind of termination.

Our approach for simulating the surface in one direction contains an infinite repetition in the other two directions. Unfortunately FHI-aims can only repeat in all three directions. In order to avoid interactions between the slabs in k_z direction and simulate a surface, one adds vacuum space to the unit cell. This is called the supercell approach. The supercell for 16 layers is illustrated in the picture at the right, where a_1 and a_2 are as explained before, but a_3 is not only as long as the slab is thick, but also contains additional vacuum space.

Theory: Density functional theory (DFT)

First Hohenberg-Kohn Theorem:

$\rho(\mathbf{r})$ can be uniquely converted into the $V_{\text{ext}}(\mathbf{r})$

Second Hohenberg-Kohn Theorem:

Ground state energy can be expressed in a density functional:

$$E^{\text{HK}}[\rho(\mathbf{r}); v_{\text{ext}}(\mathbf{r})] = T_0[\rho] + V_{\text{H}}[\rho] + \int v_{\text{ext}}(\mathbf{r})\rho(\mathbf{r})d\mathbf{r} + E_{\text{xc}}[\rho]$$

Kohn-Sham equation

Minimizing E^{HK} \rightarrow Kohn-Sham eigenfunctions $\phi_i(\mathbf{r})$:

$$E_0[\rho_0] = E_{\text{nucl}} + E_{\text{kin}} + E_{\text{H}} + E_{\text{xc}}$$

Perdew-Burke-Ernzerhof (PBE) functional

$$E_{\text{xc}}^{\text{PBE}} = \int d^3r \rho(\mathbf{r}) \epsilon_{\text{xc}}^{\text{PBE}}(r_s(\mathbf{r}), s(\mathbf{r}), \zeta(\mathbf{r}))$$

Evolution of topological surface states of thin HgTe-films with film thickness

Theory

Theory: Density functional theory (DFT)

The density functional theory was first introduced by W.Kohn et al. They found that the ground-state energy of a quantum mechanical system can be represented by a density functional. For wave function of a many-body Schrödinger equation with an Hamiltonian containing the kinetic energy, the Coulomb potential between the particles, in our case electrons, and the external Potential which is the nuclei, one can define a one-body ground states density rho. The first Hohenberg-Kohn Theorem then says that rho can be uniquely converted into the external potential and vice versa. (In other words, for one given V ext, there exists specifically one rho)

The second Hohenberg-Kohn Theorem says that the ground state energy of such a many-body system can be expressed in a density functional. T zero thereby is the kinetic energy for a system of non-interacting electrons, the rest builds the Hohenberg-Kohn potential which contains the Hartree potential and the exchange-correlation function. Note that the small v ext is the external potential just for one electron but contains all protons of the nucleus.

By minimizing this density functional we get the Kohn-Sham eigenfunctions phi i and the Kohn-Sham equation. The exchange correlation functional can not be determined exactly, so there are several approximations been done. One of them is the Perdew-Burke-Ernzerhof functional, short: PBE. It is a semilocal-density functional, which does not only depend on the density at a certain position. This means it is better for big molecules or systems in comparison to the LDA functional, which is only local (as the name local density approach indicates).

Theory: Density functional theory (DFT)

First Hohenberg-Kohn Theorem:

$\rho(\mathbf{r})$ can be uniquely converted into the $V_{\text{ext}}(\mathbf{r})$

Second Hohenberg-Kohn Theorem:

Ground state energy can be expressed in a density functional:

$$E^{\text{HFK}}[\rho(\mathbf{r}); V_{\text{ext}}(\mathbf{r})] = T_0[\rho] + V_{\text{tot}}[\rho] + \int v_{\text{ext}}(\mathbf{r})\rho(\mathbf{r})d\mathbf{r} + E_{\text{xc}}[\rho]$$

Kohn-Sham equation

Minimizing E^{HFK} → Kohn-Sham eigenfunctions $\phi_i(\mathbf{r})$:

$$E_{\text{xc}}[\rho] = E_{\text{xc,d}} + E_{\text{xc,xc}} + E_{\text{xc,l}}$$

Perdew-Burke-Ernzerhof (PBE) functional:

$$E_{\text{xc}}^{\text{PBE}} = \int d^3r \rho(\mathbf{r}) \epsilon_{\text{xc}}^{\text{PBE}}(r_s(\mathbf{r}), s(\mathbf{r}), \zeta(\mathbf{r}))$$

Theory: Spin-orbit coupling

Dirac equation:
$$\left(c\boldsymbol{\alpha} \cdot \boldsymbol{p} + c^2(\beta - 1) + V \right) \Psi = \epsilon \Psi$$

Separate Ψ into two spinors:
$$\Psi = \begin{pmatrix} \Psi_L \\ \Psi_S \end{pmatrix}$$

Substitute and dissolve:

$$\left(\boldsymbol{p} \frac{c^2}{2c^2 + \epsilon - V} \boldsymbol{p} + i \boldsymbol{p} \frac{c^2}{2c^2 + \epsilon - V} \times \boldsymbol{p} \cdot \boldsymbol{\sigma} + V \right) \Psi_L = \epsilon \Psi_L$$

First part with V is relativistic Schrödinger equation.

Expanding in $\frac{\epsilon - V}{2c^2}$ in zeroth order gives non-relativistic Schrödinger equation.

Expanding just second part in first order gives:

$$V_{SOC} = \frac{i}{4c^2} \boldsymbol{p} V \times \boldsymbol{p} \cdot \boldsymbol{\sigma}$$

Evolution of topological surface states of thin HgTe-films with film thickness

└ Theory

└ Theory: Spin-orbit coupling

The spin-orbit interaction is the interaction between a particles spin and its motion. The Dirac equation explains why it should be included in the Schrödinger equation. Here we see the Dirac equation for electrons, where alpha contains in the top at right and in the bottom at left a sigma vector with all three Pauli matrices, and beta is the matrix containing the 2D basis matrix in the left upper part and minus 2D basis matrix in the right lower part. p is the momentum. Then we separate the wave function Ψ into two spinors, large for the one that positive energies, means it represents the electrons, and is dominant for the non-relativistic limit, and small for negative energies, means positrons, which disappear in the non-relativistic limit. By substituting this into the Dirac equation and dissolve the two coupled equations we get this Schrödinger like equation.

The first part together with the V is the relativistic Schrödinger equation. By expanding it in ϵ over $2c^2$ in zeroth order and then sets ϵ to zero, it gives us the non-relativistic Schrödinger equation. By expanding only the second part of that equation above in first order, one gets the spin-orbit coupling potential.

If a structure contains heavy elements, like HgTe, it is necessary to include this potential since spin-orbit interaction also affects valence electrons. This is not the case for light elements. The SOC calculations are performed by FHI-aims after the self consistency cycle converged. In the band structure it can cause band splitting on degenerated bands.

Theory: Spin-orbit coupling

Dirac equation: $(\alpha \cdot p + c^2(\beta - 1) + V) \Psi = \epsilon \Psi$

$$\text{Separate } \Psi \text{ into two spinors: } \Psi = \begin{pmatrix} \Psi_L \\ \Psi_S \end{pmatrix}$$

Substitute and dissolve:

$$\left(p \frac{e^2}{2c^2 + \epsilon - V} p + i p \frac{e^2}{2c^2 + \epsilon - V} \times p \cdot \sigma + V \right) \Psi_L = \epsilon \Psi_L$$

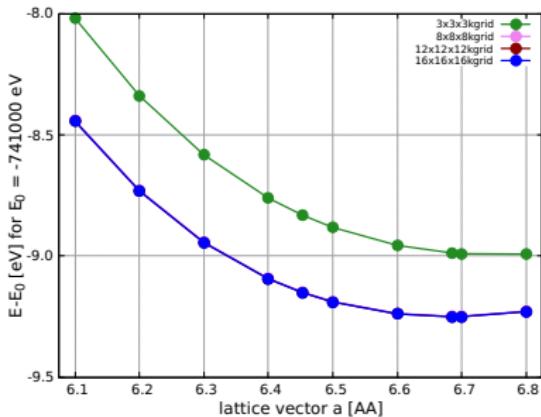
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Expanding in $\frac{\epsilon}{2c^2}$ in zeroth order gives non-relativistic Schrödinger equation.

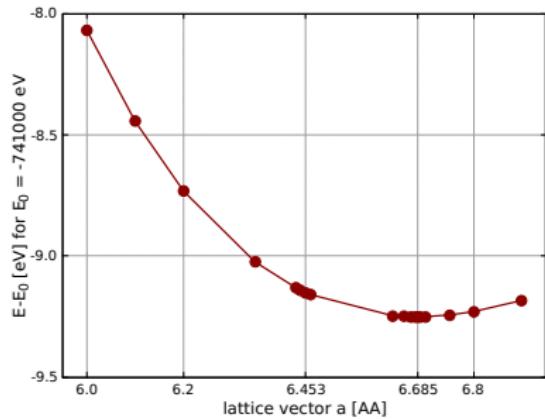
Expanding just second part in first order gives:

$$V_{\text{SOC}} = \frac{i}{4c^2} p V \times p \cdot \sigma$$

lattice constant and k-grid study part 1



Lattice constant a with respect to the total energy, calculated with 4 different k-grids.

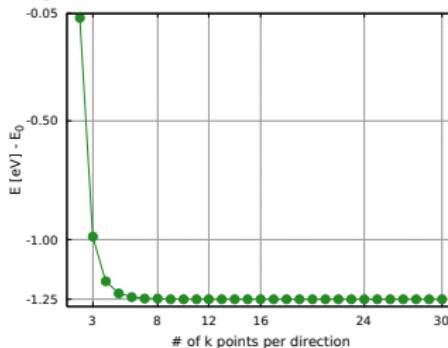


Lattice constant a with respect to the total energy. The lowest energy was found for 6.685 \AA .

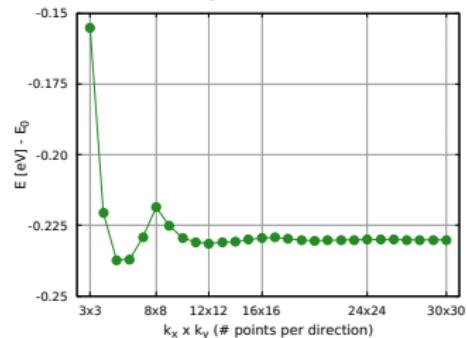
lattice constant and k-grid study part 2

Total energy $E[\text{eV}] - E_0$ (with E_0 the energy offset) as a function of k-grid spacing.

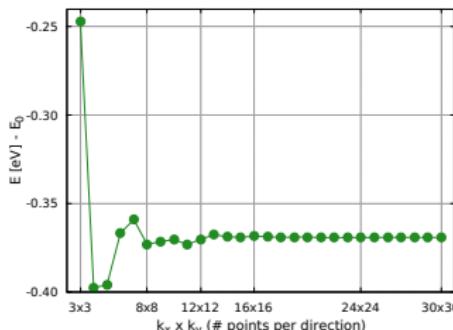
Bulk:



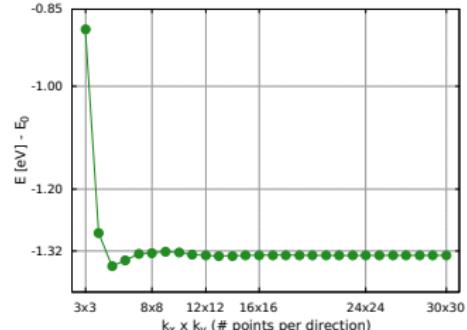
Slab with 4 layers:



Slab with 8 layers:



Slab with 16 layers:



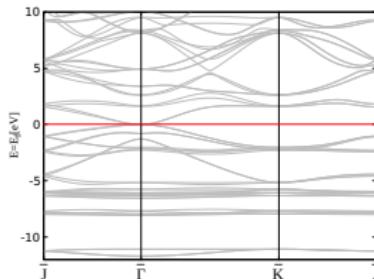
Projected bulk band structure (PBBS)

Making 40 2D Brillouin zone slices of the bulk from $k_z = 0$ to

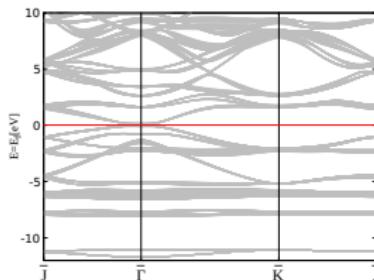
$k_z = k_{z,\max}$ where $k_{z,\max} = \frac{\pi}{a}$. Input example:

output band	0.5	0.0	0.01175	0.0	0.0	0.01175	80	J	Gamma
output band	0.0	0.0	0.01175	0.5	0.5	0.01175	80	Gamma	K
output band	0.5	0.5	0.01175	0.5	0.0	0.01175	80	K	J

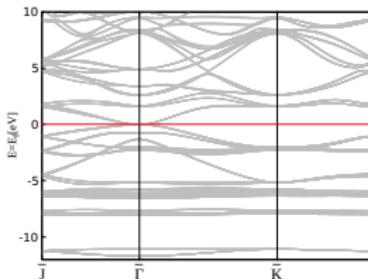
$k_z = 0$



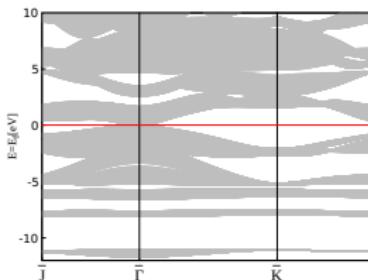
$k_z = 0$ to
 $1/4 \cdot k_{z,\max}$



$k_z = 0$ to
 $1/10 \cdot k_{z,\max}$

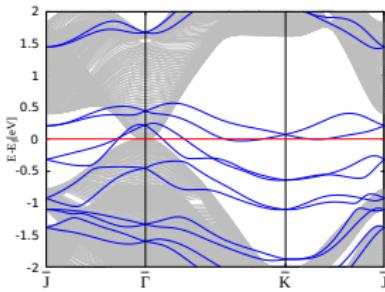


$k_z = 0$ to
 $k_{z,\max}$

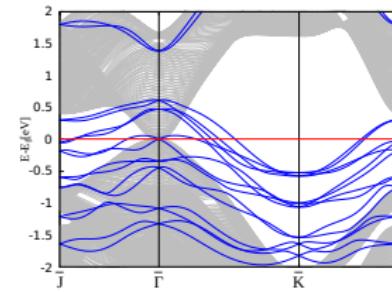


PBBS with 4 and 5 layer slabs

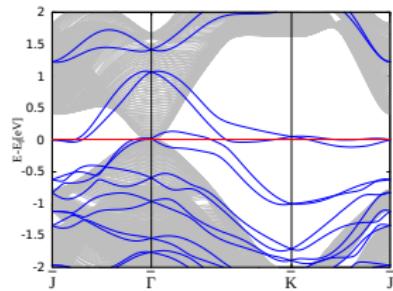
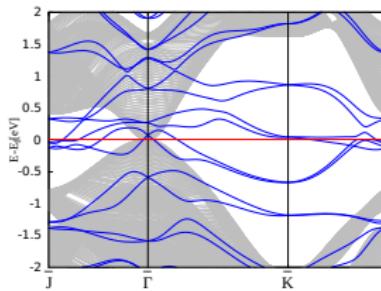
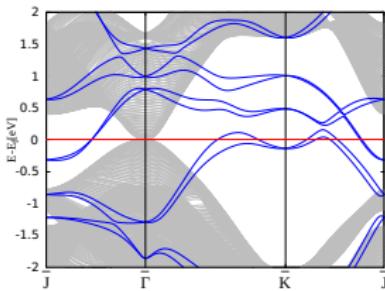
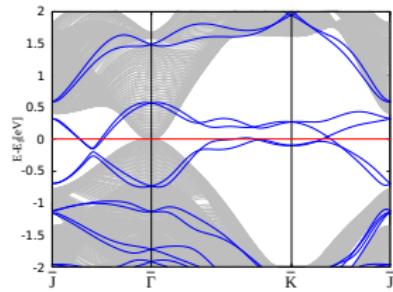
Te-Hg termination



Te-Te termination



Hg-Hg termination

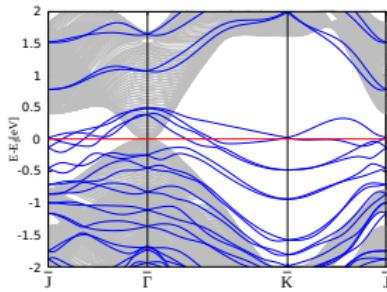


First row: without hydrogens.

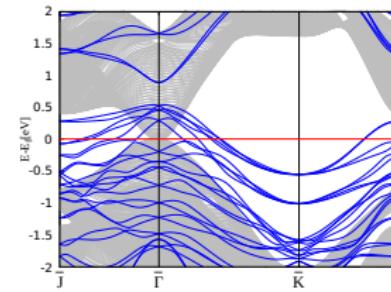
Second row: with hydrogens passivating one surface.

PBBS with 8 and 9 layer slabs

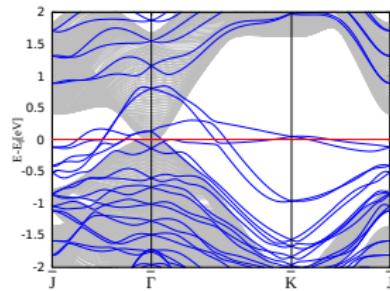
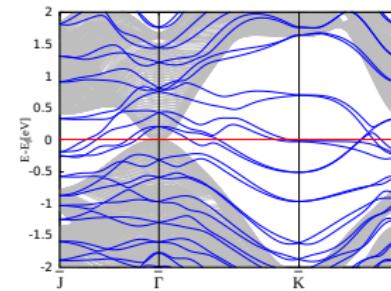
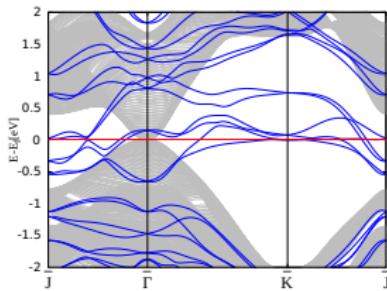
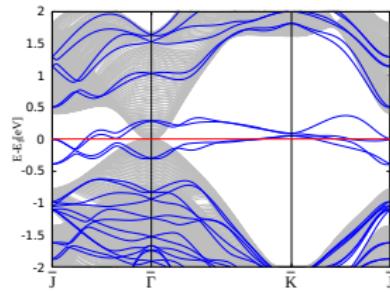
Te-Hg termination



Te-Te termination



Hg-Hg termination

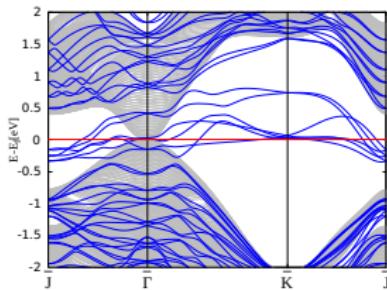
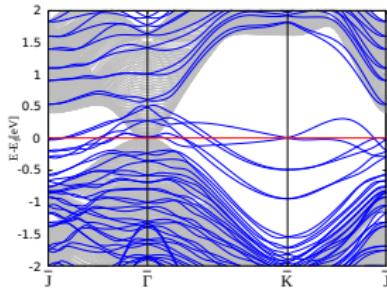


First row: without hydrogens.

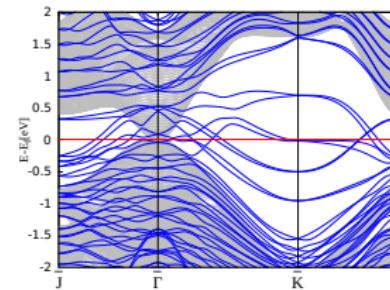
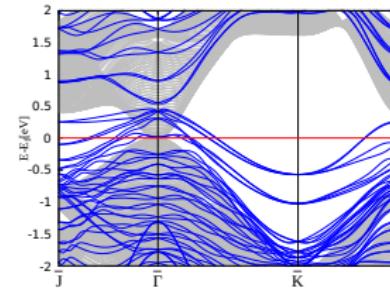
Second row: with hydrogens passivating one surface.

PBBS with 16 and 17 layer slabs

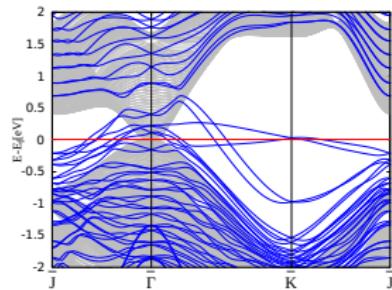
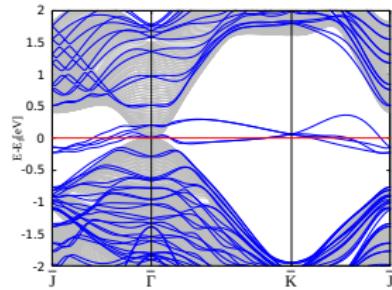
Te-Hg termination



Te-Te termination



Hg-Hg termination



First row: without hydrogens.

Second row: with hydrogens passivating one surface.

Conclusion

blub2